NSN 5962-01-152-0900

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-152-0900

Overall Length:
1.290 inches
Overall Height:
0.425 inches
Overall Width:
0.620 inches
Body Length:
0.210 inches
Body Width:
0.610 inches
Body Height:
0.310 inches
Maximum Power Dissipation Rating:
950.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Burn in and bipolar and monolithic and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Case Outline Source And Designator:
D-3 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Memory Device Type:
Rom
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:

--

NSN 5962-01-152-0900

Memory Microcircuit - Page 2 of 2



Demilitarization:

Yes - demil/mli

Fiig:

A458a0